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Volume 38 Number 8 August 2017

SEMICONDUCTOR PHYSICS

082001 ZnO_{1-x}Te_x and ZnO_{1-x}S_x semiconductor alloys as competent materials for opto-electronic and solar cell applications: a comparative analysis (5 pages)

Utsa Das and Partha P. Pal

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Feng Liang, Benling Gao, Jun Zhang, and Yu Gu

SEMICONDUCTOR MATERIALS

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Xingyi Tan, Qiang Li, and Yongdan Zhu

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Yuan Xu, Benkang Chang, Xinlong Chen, and Yunsheng Qian

SEMICONDUCTOR DEVICES

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P. Murugapandiyan, S. Ravimaran, and J. William

084002 Statistically modeling $I-V$ characteristics of CNT-FET with LASSO (4 pages)

Dongsheng Ma, Zuochang Ye, and Yan Wang

084003 Resistive switching characteristic of electrolyte-oxide-semiconductor structures (6 pages)

Xiaoyu Chen, Hao Wang, Gongchen Sun, Xiaoyu Ma, Jianguang Gao, and Wengang Wu

084004 Investigation on interfacial and electrical properties of Ge MOS capacitor with different NH₃-plasma treatment procedure (6 pages)

Xiaoyu Liu, Jingping Xu, Lu Liu, Zhixiang Cheng, Yong Huang, and Jingkang Gong

084005 Fabrication and characteristics of excellent current spreading GaN-based LED by using transparent electrode-insulator-semiconductor structure (5 pages)

Chenglin Qi, Yang Huang, Teng Zhan, Qinjin Wang, Xiaoyan Yi, and Zhiqiang Liu

084006 Theoretical simulation of performances in CIGS thin-film solar cells with cadmium-free buffer layer (6 pages)

Kang Luo, Yulin Sun, Liyu Zhou, Fang Wang, and Fang Wu

(Continued on inside back cover)

SEMICONDUCTOR INTEGRATED CIRCUITS

- 085001** **A 75 GHz regenerative dynamic frequency divider with active transformer using InGaAs/InP HBT technology** (6 pages)
Xi Wang, Bichan Zhang, Hua Zhao, Yongbo Su, Asif Muhammad, Dong Guo, and Zhi Jin
- 085002** **A high-speed power detector MMIC for E-band communication** (4 pages)
Linpu Huang, Qiang Hu, and Jian Zhang
- 085003** **A 500–600 MHz GaN power amplifier with RC–LC stability network** (4 pages)
Xinyu Ma, Baoxing Duan, and Yintang Yang
- 085004** **The design of miniaturized broadband power divider utilizing GaAs-based IPD process and equivalent circuit model** (6 pages)
Ying Lu, Liang Shen, Jiabo Wang, and Ya Shen
- 085005** **An 8 bit 1 MS/s SAR ADC with 7.72-ENOB** (6 pages)
Jihai Duan, Zhiyong Zhu, Jinli Deng, and Weilin Xu
- 085006** **A high sensitive 66 dB linear dynamic range receiver for 3-D laser radar** (6 pages)
Rui Ma, Hao Zheng, and Zhangming Zhu
- 085007** **On the design of high-speed energy-efficient successive-approximation logic for asynchronous SAR ADCs** (6 pages)
Jiaqi Yang, Ting Li, Mingyuan Yu, Shuangshuang Zhang, Fujiang Lin, and Lin He
- 085008** **A 4 Gbps current-mode transmitter for 12-bit 250 MSPS ADC** (7 pages)
Zhenhai Chen, Zongguang Yu, Jinghe Wei, Dejin Zhou, Xiaobo Su, and Jiaxuan Zou
- 085009** **Analysis of single event transient pulse-width in 65 nm commercial radiation-hardened logic cell** (5 pages)
Haisong Li, Longsheng Wu, Bo Yang, and Yihu Jiang